

Verification of the Validity of the CNTBands Tool

According to experimental data the band gap of semiconducting nanotube is inversely proportional to its radius. The simple [analytical model](#) also explained in solution for [homework Problem 3](#) indicates that the prefactor V in this dependence is the absolute value of the nearest neighbor tight-binding element in the pi-orbital approximation

$$E_g = \frac{V}{R}$$

Here CNT radius R is measured in the units of carbon-carbon bond length. If R is expressed in nanometers,

$$E_g = 0.142 \frac{V}{R}$$

The plot below, which collects data from *CNTBands* pi-orbital tight-binding simulations (dark-blue circles) demonstrates that this is indeed the case. The solid red line is the inverse dependence given by the equation above.

